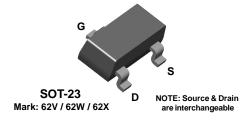


J210 J211 J212

MMBFJ210 MMBFJ211 MMBFJ212





N-Channel RF Amplifier

This device is designed for HF/VHF mixer/amplifier and applications where Process 50 is not adequate. Sufficient gain and low noise for sensitive receivers. Sourced from Process 90.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V_{DG}	Drain-Gate Voltage	25	V	
V _{GS}	Gate-Source Voltage	- 25	V	
I _{GF}	Forward Gate Current	10	mA	
T _J ,T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C	

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic		Max	Units
		J210-212	*MMBFJ210-212	
P _D	Total Device Dissipation	350	225	mW
	Derate above 25°C	2.8	1.8	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	556	°C/W

^{*}Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

200

μmhos

(continued)

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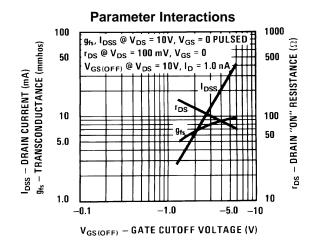
TA = 25°C unless otherwise noted

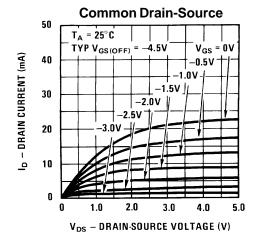
Symbol	Parameter	Test Conditions	Min	Max	Units
055.0114	DA OTERIOTION		•		
OFF CHA	RACTERISTICS				
$V_{(BR)GSS}$	Gate-Source Breakdown Voltage	$I_G = 1.0 \mu\text{A}, V_{DS} = 0$	- 25		V
I _{GSS}	Gate Reverse Current	V _{GS} = 15 V, V _{DS} = 0		- 100	pА
$V_{GS(off)}$	Gate-Source Cutoff Voltage	V _{DS} = 15 V, I _D = 1.0 nA 210 211 212	-1.0 - 2.5 - 4.0	-3.0 - 4.5 - 6.0	V V V
ON CHAR	RACTERISTICS Zero-Gate Voltage Drain Current*	V _{DS} = 15 V, V _{GS} = 0 210	2.0	15	m A
		V _{DS} = 15 V, V _{GS} = 0 210 211 212	2.0 7.0 15	15 20 40	m A m A m A
IDSS		211	7.0	20	m A

 $V_{DS} = 15 \text{ V}, V_{GS} = 0, f = 1.0 \text{ kHz}$

Typical Characteristics

Common Source Output

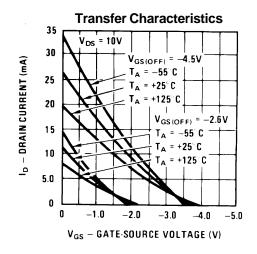


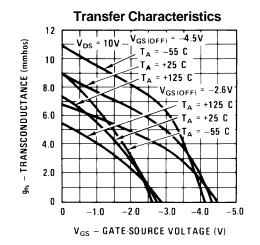


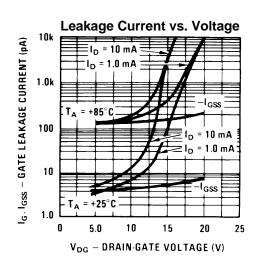
^{*}Pulse Test: Pulse Width \leq 300 μ S

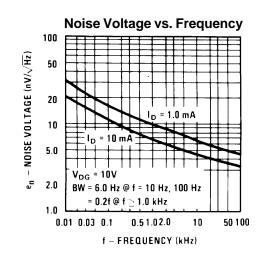
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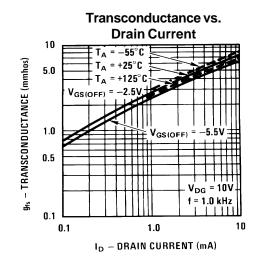
Typical Characteristics (continued)

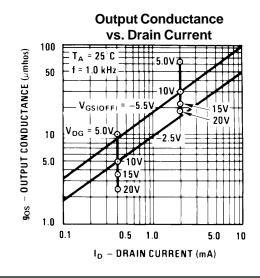






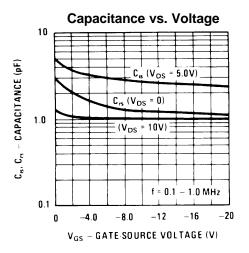




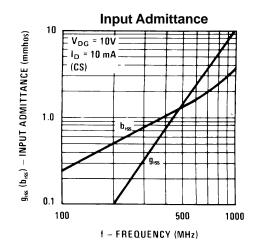


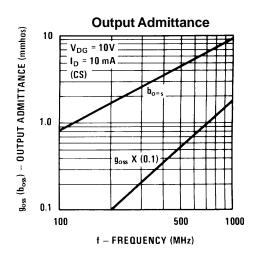
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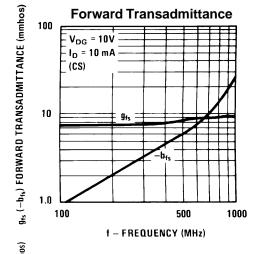
Typical Characteristics (continued)

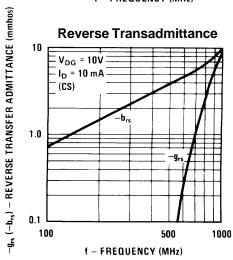


Common Source Characteristics



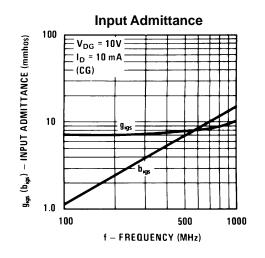


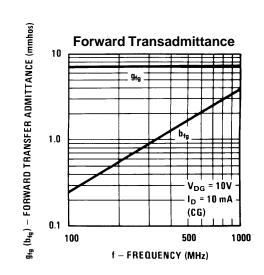


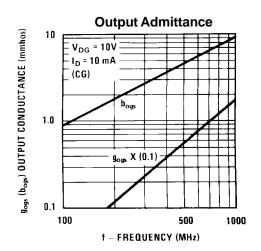


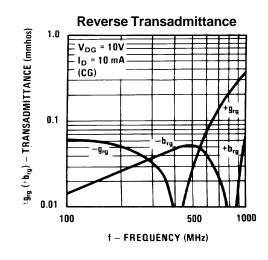
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Common Gate Characteristics









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